

## PATENT ASSIGNMENT COVER SHEET

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EPAS ID: PAT3053911

<b>SUBMISSION TYPE:</b>	NEW ASSIGNMENT
<b>NATURE OF CONVEYANCE:</b>	ASSIGNMENT
<b>CONVEYING PARTY DATA</b>	
<b>Name</b>	<b>Execution Date</b>
PENG-FU HSU	02/17/2009
KANG-CHENG LIN	05/18/2009
KUO-TAI HUANG	02/23/2009
<b>RECEIVING PARTY DATA</b>	
<b>Name:</b>	TAIWAN SEMICONDUCTOR MANUFACTURING COMPANY, LTD.
<b>Street Address:</b>	NO. 8, LI-HSIN RD. 6
<b>Internal Address:</b>	SCIENCE-BASED INDUSTRIAL PARK
<b>City:</b>	HSIN-CHU
<b>State/Country:</b>	TAIWAN
<b>Postal Code:</b>	300-77
<b>PROPERTY NUMBERS Total: 1</b>	
<b>Property Type</b>	<b>Number</b>
<b>Application Number:</b>	14507362
<b>CORRESPONDENCE DATA</b>	
<b>Fax Number:</b>	(214)200-0853
<i>Correspondence will be sent to the e-mail address first; if that is unsuccessful, it will be sent using a fax number, if provided; if that is unsuccessful, it will be sent via US Mail.</i>	
<b>Phone:</b>	214-651-5000
<b>Email:</b>	ipdocketing@haynesboone.com
<b>Correspondent Name:</b>	HAYNES AND BOONE, LLP
<b>Address Line 1:</b>	2323 VICTORY AVENUE
<b>Address Line 2:</b>	SUITE 700
<b>Address Line 4:</b>	DALLAS, TEXAS 75219
<b>ATTORNEY DOCKET NUMBER:</b>	2008-0469 AND -0471-D2
<b>NAME OF SUBMITTER:</b>	KYLE HOWARD
<b>SIGNATURE:</b>	/KYLE HOWARD/
<b>DATE SIGNED:</b>	10/06/2014
<b>Total Attachments: 4</b>	
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**ASSIGNMENT**

WHEREAS, we,

- |     |                |    |  |
|-----|----------------|----|--|
| (1) | Peng-Fu Hsu    | of | No. 141, Chang-Chun Street<br>Hsinchu, Taoyuan City, Taiwan, R.O.C.                          |
| (2) | Kang-Cheng Lin | of | 4F, No. 5, Alley 5, Lane 421, Jhonghe Road<br>Yonghe City, Taipei County 234, Taiwan, R.O.C. |
| (3) | Kuo-Tai Huang  | of | 17 Alley 37 Lane 72, Kwanghua 2nd Street<br>Hsinchu, Taiwan, R.O.C.                          |

have invented certain improvements in

**METHOD OF FABRICATING DUAL HIGH-K METAL GATES FOR MOS DEVICES**

for which we have executed an application for Letters Patent of the United States of America,

  X   of even date filed herewith; and  
  x   filed on 04/16/2009 and assigned application number 12/424,739; and

WHEREAS, we authorize the attorney of record to update this document to include Patent Office information as deemed necessary (i.e., filing date, serial number, etc.);

WHEREAS, Taiwan Semiconductor Manufacturing Company, Ltd., ("TSMC"), No. 8, Li-Hsin Rd. 6, Science-Based Industrial Park Hsin-Chu, Taiwan 300-77, Republic of China, is desirous of obtaining the entire right, title, and interest in, to and under the said invention and the said application in the United States of America and in any and all countries foreign thereto;

NOW, THEREFORE, for One Dollar (\$1.00) and other good and valuable consideration, the receipt and sufficiency of which is hereby acknowledged, and other good and valuable consideration, we have sold, assigned, transferred and set over, and by these presents do hereby sell, assign, transfer and set over, unto the said TSMC, its successors, legal representatives, and assigns, the entire right, title, and interest in, to and under the said invention, and the said application, and all divisional, renewal, substitutional, and continuing applications thereof, and all Letters Patent of the United States of America which may be granted thereon and all reissues and extensions thereof, and all applications for Letters Patent which may be filed for said invention in any country or countries foreign to the United States of America, and all extensions, renewals, and reissues thereof, and all prior patents and patent applications from which a filing priority of the above-described patent application may be obtained, including the right to collect past damages; and we hereby authorize and request the Commissioner of Patents of the United States of America, and any official of any country or countries foreign to the United States of America, whose duty it is to issue patents on applications as aforesaid, to issue all Letters Patent for said invention to the said TSMC, its successors, legal representatives and assigns, in accordance with the terms of this instrument.

AND WE HEREBY covenant that we have full right to convey the entire interest herein assigned, and that we have not executed, and will not execute, any agreement in conflict herewith.

Docket No.: 2008-0469 (2008-0471) / 24061.1109  
Customer No.: 42717

AND WE HEREBY further covenant and agree that we will communicate to said TSMC, its successors, legal representatives and assigns, any facts known to us respecting said invention, and testify in any legal proceedings, sign all lawful papers, execute all divisional, renewal, substitutional, continuing, and reissue applications, make all rightful declarations and/or oaths and generally do everything possible to aid the said TSMC, its successors, legal representatives and assigns, to obtain and enforce proper patent protection for said invention in all countries.

Inventor Name: Peng-Fu Hsu

Residence Address: No. 141, Chang-Chun Street  
Hsinchu, Taoyuan City, Taiwan, R.O.C.

Dated: 2/17/2009

Peng-Fu Hsu  
Inventor Signature

Inventor Name: Kang-Cheng Lin

Residence Address: 4F, No. 5, Alley 5, Lane 421, Jhonghe Road  
Yonghe City, Taipei County 234, Taiwan, R.O.C.

Dated: \_\_\_\_\_

\_\_\_\_\_  
Inventor Signature

Inventor Name: Kuo-Tai Huang

Residence Address: 17 Alley 37 Lane 72, Kwanghua 2nd Street  
Hsinchu, Taiwan, R.O.C.

Dated: 2/23/2009

Kuo-Tai Huang  
Inventor Signature

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AND WE HEREBY covenant that we have full right to convey the entire interest herein assigned, and that we have not executed, and will not execute, any agreement in conflict herewith.

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Inventor Name: Peng-Fu Hsu

Residence Address: No. 141, Chang-Chun Street  
Hsinchu, Taoyuan City, Taiwan, R.O.C.

Dated: \_\_\_\_\_

\_\_\_\_\_  
Inventor Signature

Inventor Name: Kang-Cheng Lin

Residence Address: 4F, No. 5, Alley 5, Lane 421, Jhonghe Road  
Yonghe City, Taipei County 234, Taiwan, R.O.C.

Dated: 5/18/2009

*Kang-Cheng Lin*  
\_\_\_\_\_  
Inventor Signature

Inventor Name: Kuo-Tai Huang

Residence Address: 17 Alley 37 Lane 72, Kwanghua 2nd Street  
Hsinchu, Taiwan, R.O.C.

Dated: \_\_\_\_\_

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Inventor Signature